

MAX14721/ MAX14722/ MAX14723

High-Accuracy, Adjustable Power Limiter

General Description

The MAX14721–MAX14723 adjustable overvoltage, undervoltage, and overcurrent protection devices guard systems against overcurrent faults in addition to positive overvoltage and reverse-voltage faults. When used with an optional external p-channel MOSFET, the devices also protect downstream circuitry from voltage faults up to +60V, -60V (for -60V external pFET rating). The devices feature a low, 76mΩ, on-resistance integrated FET.

During startup, the devices are designed to charge large capacitances on the output in a continuous mode for applications where large reservoir capacitors are used on the inputs to downstream devices. Additionally, the MAX14721–MAX14723 feature a dual-stage, current-limit mode in which the current is continuously limited to 1x, 1.5x, and 2x the programmed limit, respectively, for a short time after startup. This enables faster charging of large loads during startup.

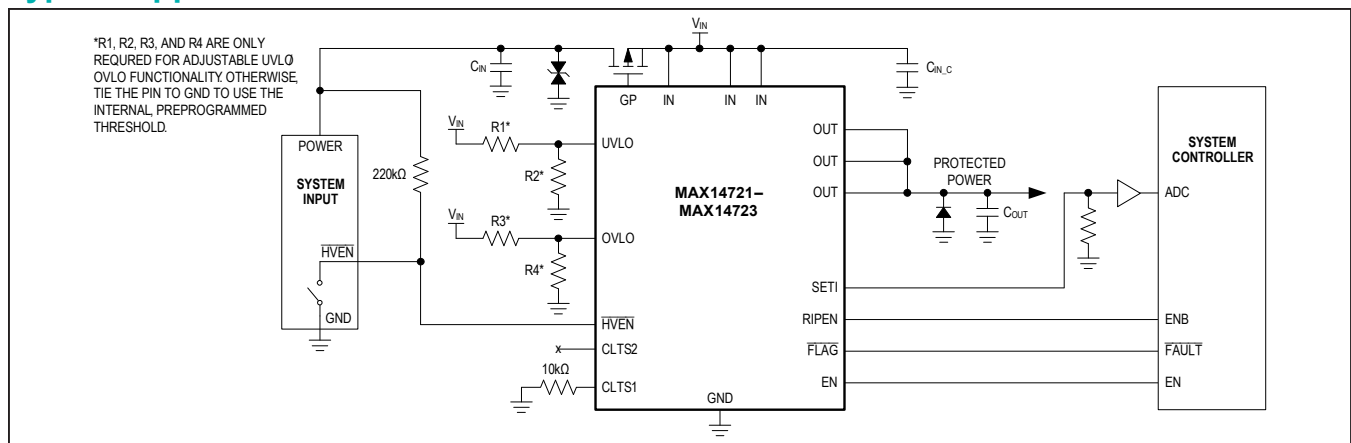
The MAX14721–MAX14723 also feature reverse-current and overtemperature protection. The devices are available in a 20-pin (5mm x 5mm) TQFN package and operate over a -40°C to 125°C temperature range.

Applications

Industrial Power Systems
Control and Automation
Motion System Drives
Human Machine Interfaces
High-Power Applications

Ordering Information appears at end of data sheet.

Typical Application Circuit



Benefits and Features

- Robust, High-Power Protection Reduces System Downtime
 - Wide Input Supply Range: +5.5V to +60V
 - Programmable Input Supply Overvoltage Setting Up to 40V
 - Thermal Foldback Current-Limit Protection
 - Negative Input Tolerance to -60V (for -60V External pFET Rating)
 - Low 76mΩ (typ) R_{ON}
 - Reverse Current-Blocking Protection with External pFET
- Enables Safer Startup By Preventing Overheating of FETs
 - Dual-Stage Current Limiting
 - 1.0x Startup Current (MAX14721)
 - 1.5x Startup Current (MAX14722)
 - 2.0x Startup Current (MAX14723)
- Flexible Design Enables Reuse and Less Requalification
 - Adjustable OVLO and UVLO Thresholds
 - Programmable Forward Current Limit From 0.2A to 2A with ±15% Accuracy Over Full Temperature Range
 - Normal and High-Voltage Enable Inputs (EN and HVEN)
 - Protected External pFET Gate Drive
- Saves Board Space and Reduces External BOM Count
 - 20-Pin, 5mm x 5mm TQFN Package
 - Integrated nFET

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Absolute Maximum Ratings

(All voltages referenced to GND.)

IN (Note 1).....-0.3V to +60.5V
 OUT.....-0.3V to $V_{IN} + 0.3V$
 \overline{HVEN} (Note 1).....-0.3V to $V_{IN} + 0.3V$
 GP.....max (-0.3V, $V_{IN} - 20V$) to $V_{IN} + 0.3V$
 \overline{UVLO} , \overline{OVLO}-0.3V to min ($V_{IN} + 0.3V$, 20V)
 \overline{FLAG} , EN, RIPEN, CLTS1, CLTS2.....-0.3V to +6V
 Maximum Current into IN (DC) (Note 2).....2A

SETI.....-0.3V to min($V_{IN} + 0.3V$, 6V)
 Continuous Power Dissipation ($T_A = +70^\circ C$)
 TQFN (derate 31.3mW/ $^\circ C$ above $+70^\circ C$).....2500mW
 Operating Temperature Range..... $-40^\circ C$ to $+125^\circ C$
 Junction Temperature..... $+150^\circ C$
 Storage Temperature Range..... $-65^\circ C$ to $+150^\circ C$
 Lead Temperature (soldering, 10s)..... $+300^\circ C$
 Soldering Temperature (reflow)..... $+260^\circ C$

Note 1: An external pFET or diode is required to achieve negative input protection.

Note 2: DC current-limited by R_{SETI} as well as by thermal design.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Package Information

PACKAGE TYPE: 20 TQFN	
Package Code	T2055+3C
Outline Number	21-0140
Land Pattern Number	90-0008
THERMAL RESISTANCE, FOUR-LAYER BOARD	
Junction to Ambient (θ_{JA})	32 $^\circ C/W$
Junction to Case (θ_{JC})	3 $^\circ C/W$

For the latest package outline information and land patterns (footprints), go to www.maximintegrated.com/packages. Note that a "+", "#", or "-" in the package code indicates RoHS status only. Package drawings may show a different suffix character, but the drawing pertains to the package regardless of RoHS status.

Package thermal resistances were obtained using the method described in JEDEC specification JESD51-7, using a four-layer board. For detailed information on package thermal considerations, refer to www.maximintegrated.com/thermal-tutorial.

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Electrical Characteristics

($V_{IN} = 5.5V$ to $60V$, $T_A = -40^{\circ}C$ to $+125^{\circ}C$, unless otherwise noted. Typical values are at $V_{IN} = 24V$, $T_A = +25^{\circ}C$.) (Note 3)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
POWER SUPPLY						
IN Voltage Range	V_{IN}		5.5		60	V
Shutdown IN Current	I_{SHDN}	$V_{EN} = 0V$, $V_{HVEN} = 5V$, $V_{IN} < 40V$		5.25	15	μA
		$V_{EN} = 0V$, $V_{HVEN} = 5V$		5.25	150	
Supply Current	I_{IN}	$V_{IN} = V_{OUT} = 24V$, $V_{HVEN} = 0V$		1.4	1.9	mA
Shutdown OUT Current	I_{OFF}	$V_{EN} = 0V$, $V_{HVEN} = 5V$		50	100	μA
UVLO, OVLO						
Internal UVLO Trip Level	V_{UVLO}	V_{IN} falling, UVLO trip point	11.5	12	12.5	V
		V_{IN} rising	11.9	12.4	13	
UVLO Hysteresis		% of typical UVLO		3		%
Internal OVLO Trip Level	V_{OVLO}	V_{IN} falling	32.1	33.8	35.6	V
		V_{IN} rising, OVLO trip point	34.5	36	37.4	
OVLO Hysteresis		% of typical OVLO		6		%
External UVLO Adjustment Range (Note 4)			5.5		24	V
External UVLO Select Voltage	V_{UVLO_SEL}		0.15	0.38	0.5	V
External UVLO Leakage Current	I_{UVLO_LEAK}		-250		+250	nA
External OVLO Adjustment Range (Note 4)			6		40	V
External OVLO Select Voltage	V_{OVLO_SEL}		0.15	0.38	0.5	V
External OVLO Leakage Current	I_{OVLO_LEAK}		-250		+250	nA
External UVLO/OVLO Set Voltage	V_{SET}		1.18	1.22	1.27	V
Undervoltage Trip Level on OUT	V_{UVLO_OUT}	V_{OUT} falling, UVLO trip point	11.5	12	12.5	V
		V_{OUT} rising	11.9	12.4	13	
GP						
Gate Clamp Voltage	V_{GP}		10	16.1	20	V
Gate Active Pullup				25	50	Ω
Gate Active Pulldown		$V_{EN} = 5V$	50	110		μA
Shutdown Gate Active Pullup		$V_{EN} = 0V$, $V_{HVEN} = 5V$		2.2		M Ω

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Electrical Characteristics (continued)

($V_{IN} = 5.5V$ to $60V$, $T_A = -40^{\circ}C$ to $+125^{\circ}C$, unless otherwise noted. Typical values are at $V_{IN} = 24V$, $T_A = +25^{\circ}C$.) (Note 3)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
INTERNAL FETs						
Internal FETs On-Resistance	R_{ON}	$I_{LOAD} = 100mA$, $V_{IN} \geq 10V$, $T_A = +25^{\circ}C$		76	101	m Ω
Current Limit Adjustment Range	I_{LIM}		0.2		2	A
Current Limit Accuracy	I_{LIM_ACC}	$0.3A \leq I_{LIM} \leq 2A$ ($T_A = +25^{\circ}C$)	-10		+10	%
		$0.2A \leq I_{LIM} \leq 2A$	-15		+15	
FLAG Assertion Drop Voltage Threshold	V_{FA}	Increase in ($V_{IN} - V_{OUT}$) drop until FLAG asserts, $V_{IN} = 24V$		480		mV
Reverse Current-Blocking Threshold	V_{RIB}	$V_{IN} - V_{OUT}$	-4	-9	-14	mV
Reverse Current-Blocking Response Time	t_{RIB}	($V_{IN} - V_{OUT}$) changes from 0.2V to -0.3V in 100nsec, t_{RIB} is the interval between $V_{IN} = V_{OUT}$ and $V_{IN-GP} = 0.5V$ without capacitive load on GP		1	1.55	μs
Reverse-Blocking Supply Current	I_{RBS}	$V_{OUT} = 24V$		2000	3900	μA
LOGIC INPUT (\overline{HVEN}, CLTS1, CLTS2, EN, RIPEN)						
\overline{HVEN} Threshold Voltage	$V_{\overline{HVEN_TH}}$		1	2	3.1	V
\overline{HVEN} Threshold Hysteresis				5		%
\overline{HVEN} Input Leakage Current	$I_{\overline{HVEN_LEAK}}$	$V_{\overline{HVEN}} = 60V$		46	67	μA
EN, RIPEN, CLTS1, CLTS2 Input Logic-High	V_{IH}		1.4			V
EN, RIPEN, CLTS1, CLTS2 Input Logic-Low	V_{IL}				0.4	V
EN Input Leakage Current	I_{EN_LEAK}	$V_{EN} = 0V, 5V$	-1		+1	μA
RIPEN Leakage Current	I_{RIPEN_LEAK}	RIPEN = GND		25		μA
CLTS_ Leakage Current		CLTS_ = GND		25		μA
LOGIC OUTPUT (\overline{FLAG})						
Logic-Low Voltage		$I_{SINK} = 1mA$			0.4	V
Input Leakage Current		$V_{IN} = 5.5V$, FLAG deasserted			1	μA
SETI						
$R_{SETI} \times I_{LIM}$	V_{RI}	See <i>Setting the Current-Limit Threshold</i> section		1.5		V
Current Mirror Output Ratio	C_{IRATIO}				8333	

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Electrical Characteristics (continued)

($V_{IN} = 5.5V$ to $60V$, $T_A = -40^\circ C$ to $+125^\circ C$, unless otherwise noted. Typical values are at $V_{IN} = 24V$, $T_A = +25^\circ C$.) (Note 3)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
DYNAMIC PERFORMANCE (NOTE 5)						
Switch Turn-On Time	t_{ON}	$V_{IN} = 24V$, switch OFF to ON, $R_{LOAD} = 240\Omega$, $I_{LIM} = 1A$, $C_{OUT} = 4.7\mu F$, V_{OUT} from 20% to 80% of V_{IN}		118		μs
Fault Recovery nFET Turn-on Time	t_{ON_NFET}	$V_{OUT} > V_{UVLO_OUT}$, turn-on delay after fault timers expired		420	730	μs
Reverse-Current Fault Recovery Time	t_{REV_REC}		2.18	2.40	2.64	ms
OVP Switch Response Time	t_{OVP_RES}			3		μs
Overcurrent Switch Response time	t_{OCP_RES}	$I_{LIM} = 2A$		3		μs
Startup Timeout	t_{STO}	Initial start current-limit foldback timeout (Figure 1)	1090	1200	1320	ms
Startup Initial Time	t_{STI}	Current is continuously limited to $1x/1.5x/2x$ in this interval (Figure 1)	21.8	24	26.4	ms
IN Debounce Time	t_{DEB}	Interval between $V_{IN} > V_{UVLO}$ and $V_{OUT} = 10\%$ of V_{IN} (Figure 2)	0.25	0.50	0.75	ms
Blanking Time	t_{BLANK}	(Figure 3 and Figure 4)	21.8	24	26.4	ms
Autoretry Time	t_{RETRY}	(Figure 3, Note 6)	554	720	792	ms
THERMAL PROTECTION						
Thermal Foldback	T_{J_FB}			145		$^\circ C$
Thermal Shutdown	T_{J_MAX}			170		$^\circ C$
Thermal-Shutdown Hysteresis				20		$^\circ C$

Note 3: All devices are 100% production-tested at $T_A = +25^\circ C$. Specifications over the operating temperature range are guaranteed by design.

Note 4: Not production-tested, user-adjustable. See the [Overvoltage Lockout \(OVLO\)](#) and [Undervoltage Lockout \(UVLO\)](#) sections.

Note 5: All timing is measured using 20% and 80% levels, unless otherwise specified.

Note 6: The autoretry time-to-blanking time ratio is fixed and is equal to 30.

Timing Diagrams

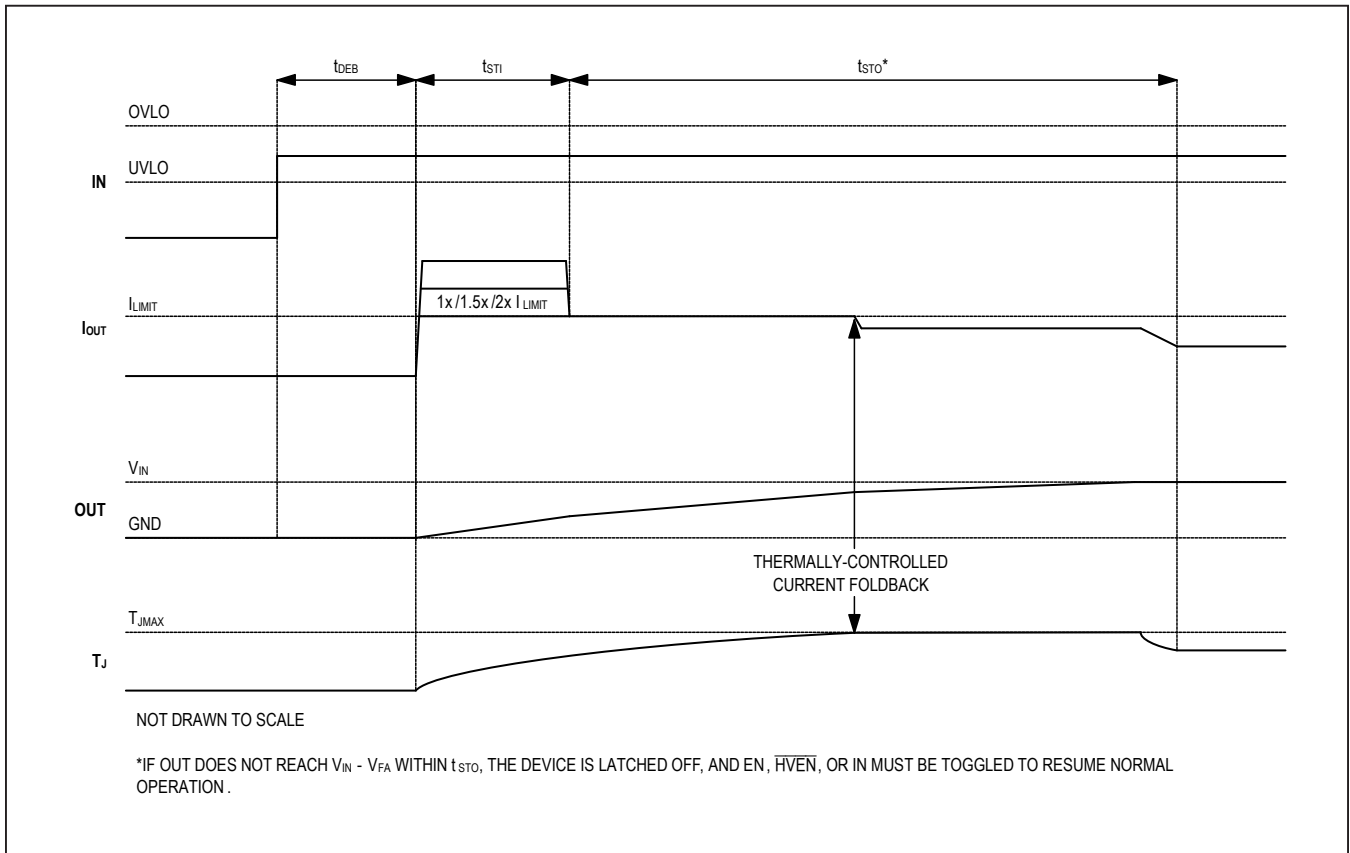


Figure 1. Startup Timing

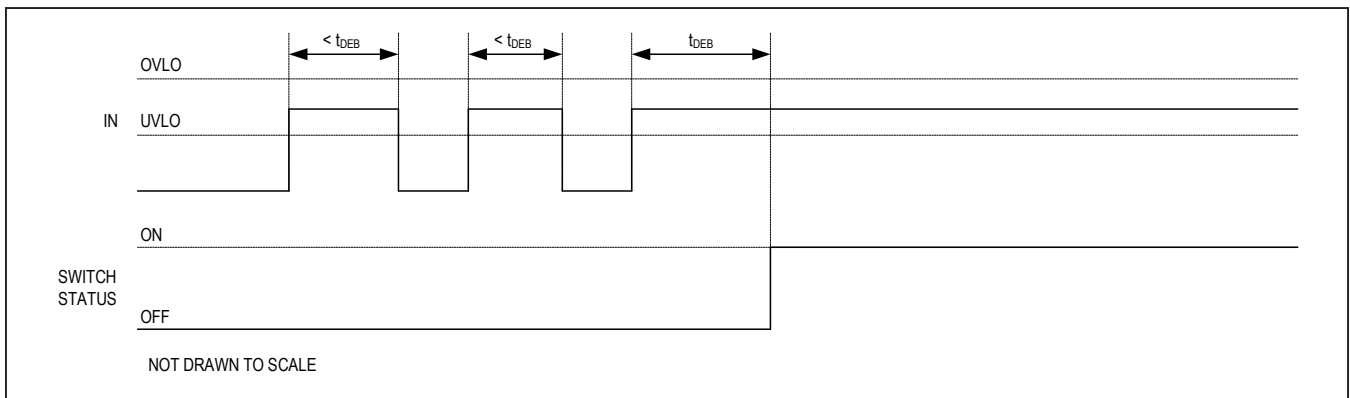
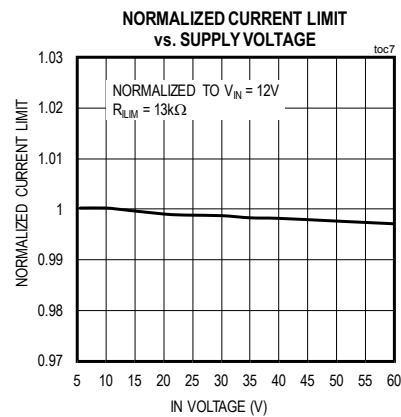
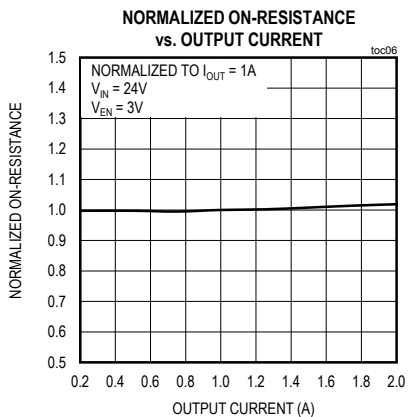
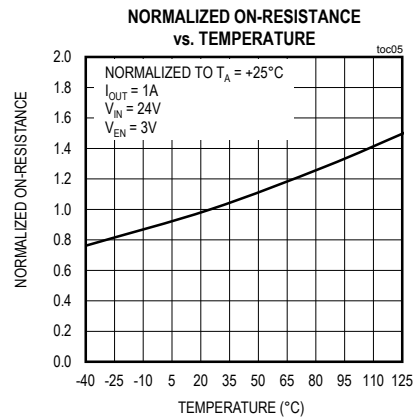
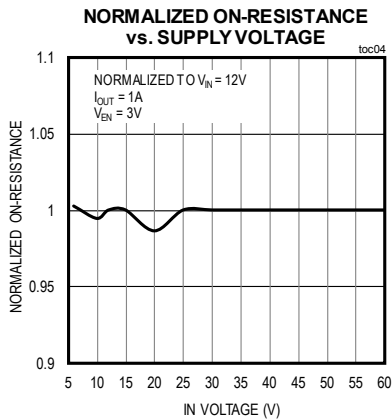
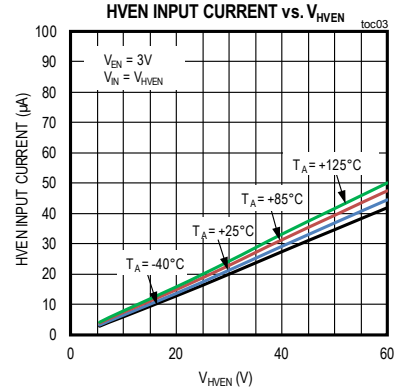
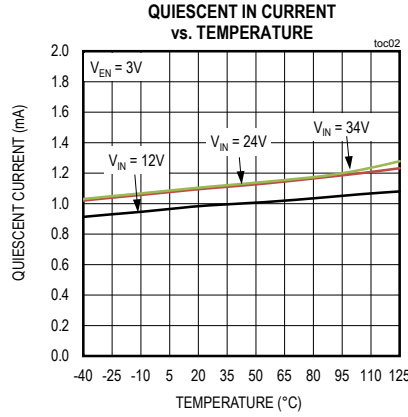
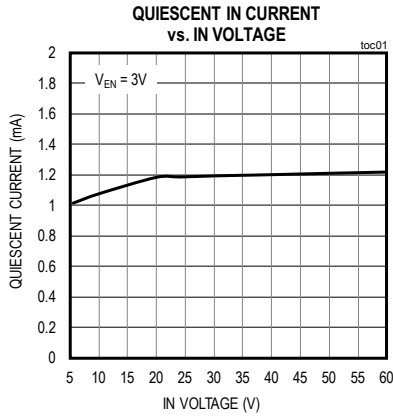


Figure 2. Debounce Timing

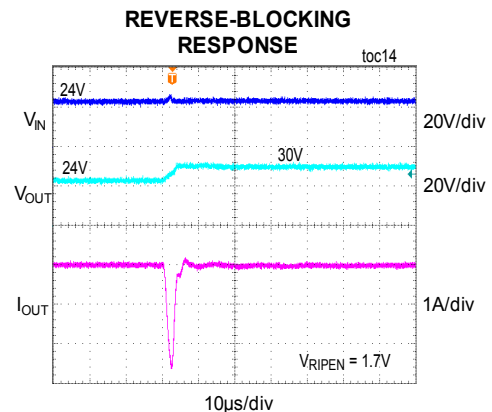
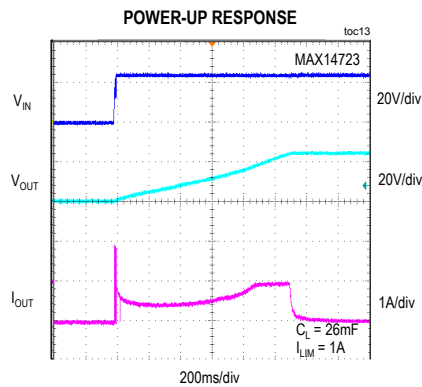
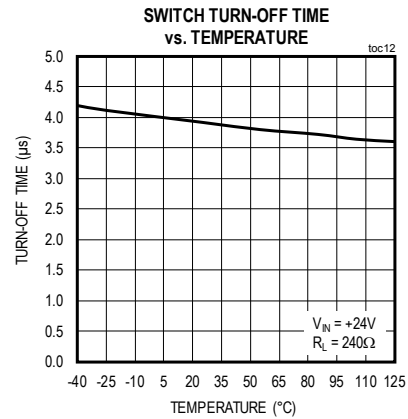
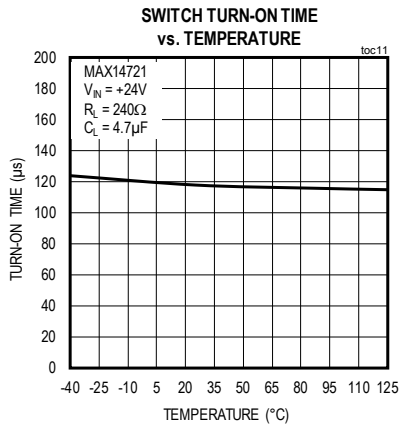
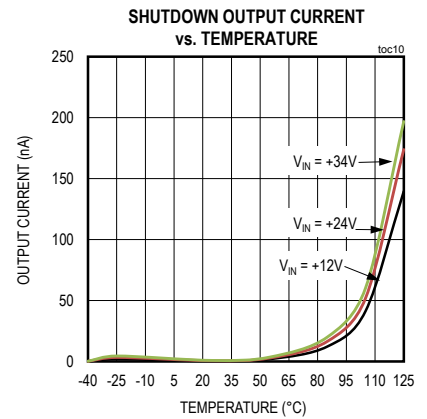
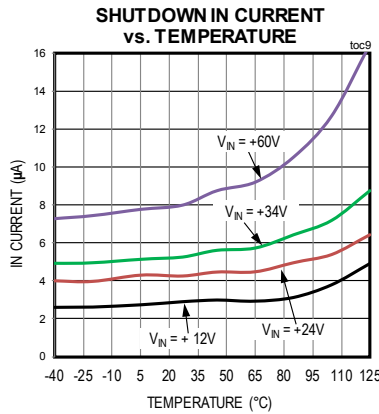
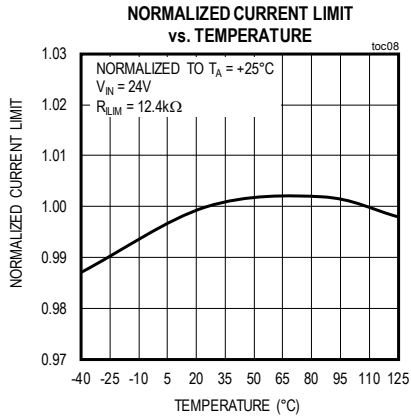
Typical Operating Characteristics

($V_{IN} = 12V$, $C_{IN} = 1\mu F$, $C_{OUT} = 4.7\mu F$, $T_A = +25^\circ C$, unless otherwise noted.)



Typical Operating Characteristics (continued)

($V_{IN} = 12V$, $C_{IN} = 1\mu F$, $C_{OUT} = 4.7\mu F$, $T_A = +25^\circ C$, unless otherwise noted.)

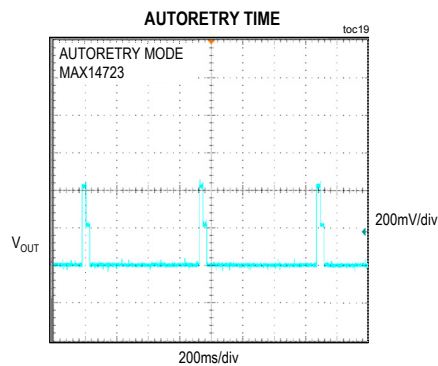
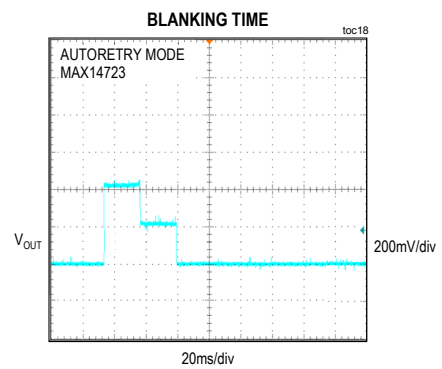
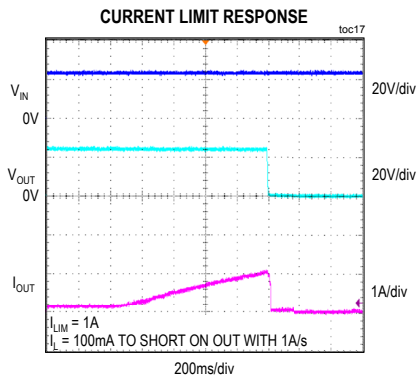
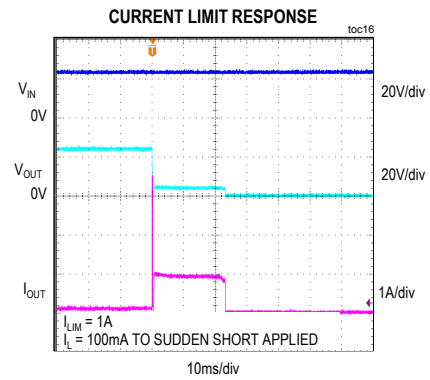
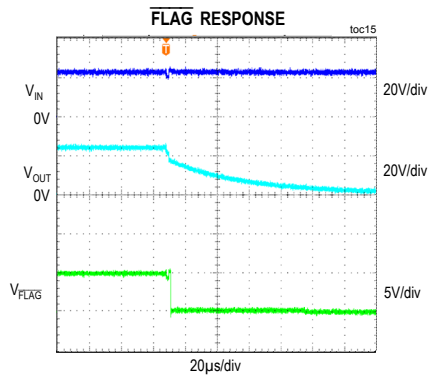


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Typical Operating Characteristics

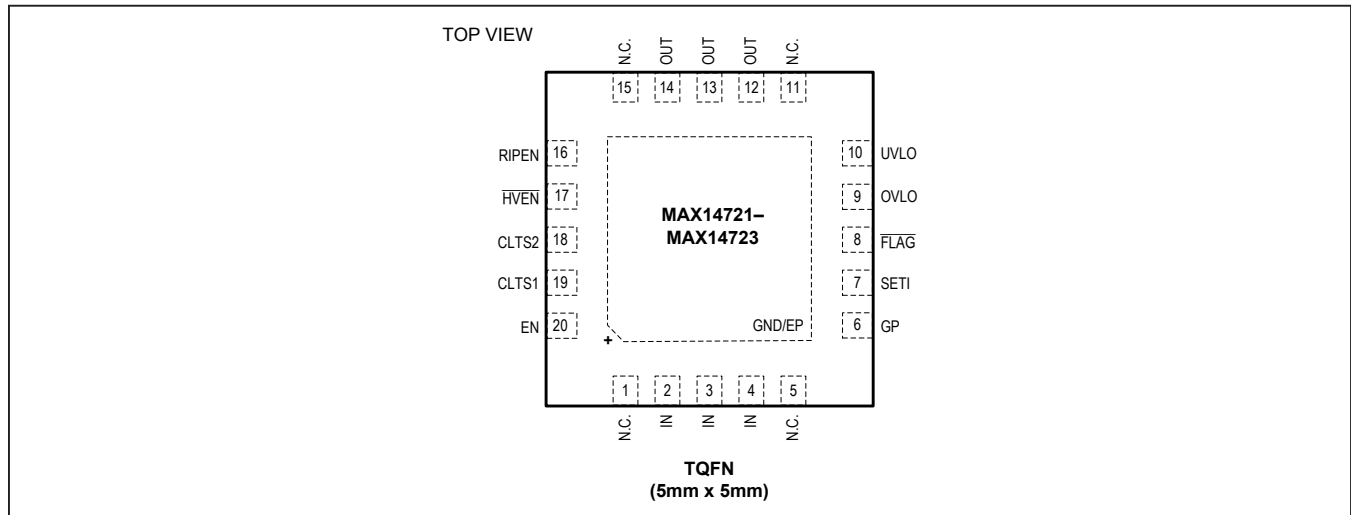
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Pin Configurations



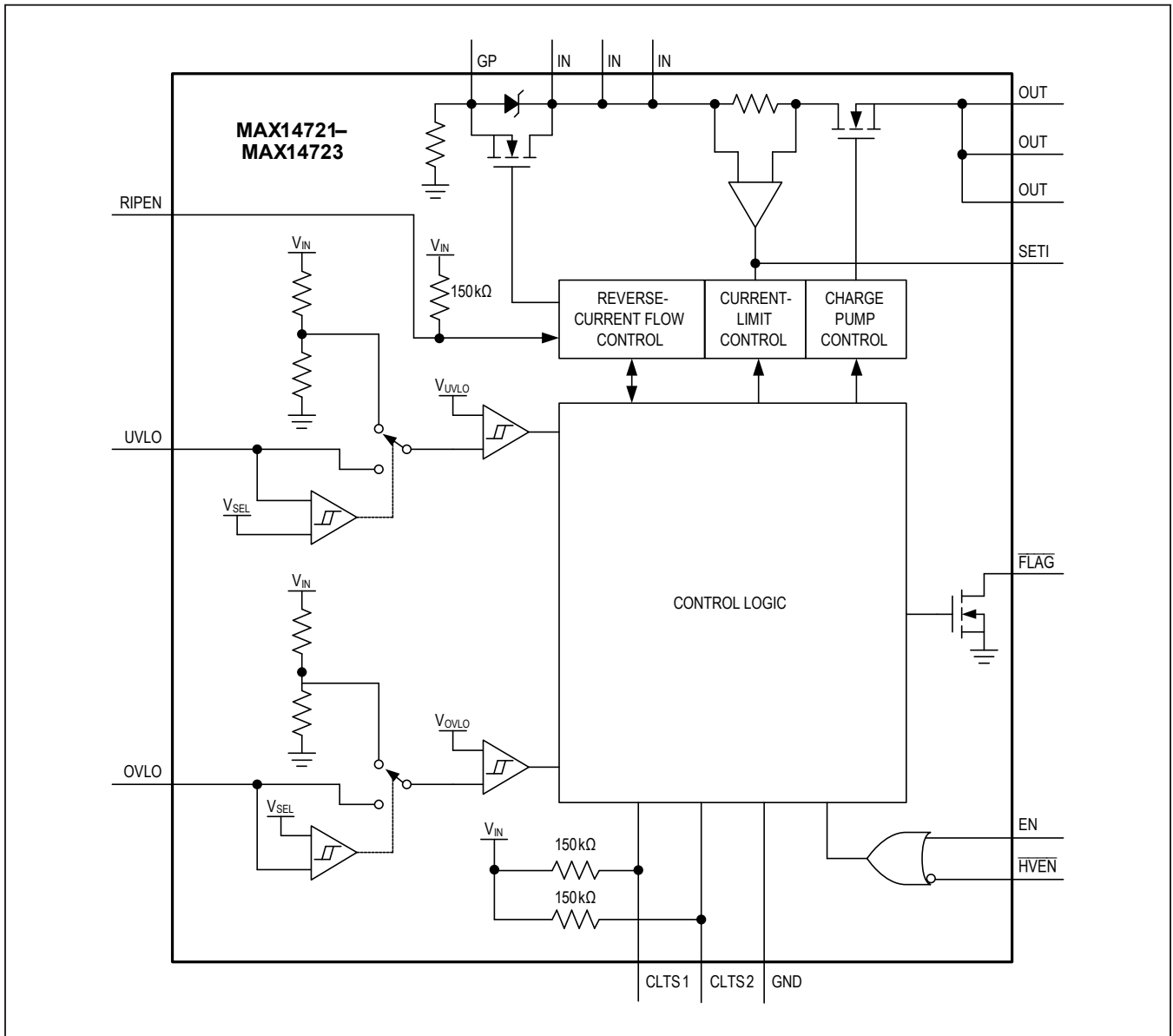
Pin Description

PIN	NAME	FUNCTION
1, 5, 11, 15	N.C.	Not Connected
2, 3, 4	IN	Switch Input. Bypass IN to ground with a 1 μ F ceramic capacitor for \pm 15kV Human Body Model ESD protection on IN. In applications in which an external pFET is used, a 4.7 μ F capacitor should be placed at the drain of the pFET and a reduced capacitor of 10nF to 100nF should be placed at IN. The maximum slew rate allowed at IN is 30V/ μ s. IN serves as the under/overvoltage sensed input when preprogrammed UVLO/OVLO is used.
6	GP	Gate Driver Output for External pFET
7	SETI	Overload Current-Limit Adjust. Connect a resistor from SETI to GND to program the overcurrent limit. SETI must be connected to a resistor. If SETI is connected to GND during startup, then the switch does not turn on. Do not connect more than 30pF to SETI.
8	$\overline{\text{FLAG}}$	Open-Drain Fault Indicator Output. $\overline{\text{FLAG}}$ asserts low when the $V_{\text{IN}} - V_{\text{OUT}}$ voltage exceeds V_{FA} , reverse-current is detected, thermal shutdown mode is active, OVLO or UVLO threshold is reached, or SETI is connected to GND.
9	OVLO	Externally-Programmable Overvoltage Lockout Threshold. Connect OVLO to GND to use the default internal OVLO threshold. Connect OVLO to an external resistor-divider to define a threshold externally and override the preset internal OVLO threshold.
10	UVLO	Externally-Programmable Undervoltage Lockout Threshold. Connect UVLO to GND to use the default internal UVLO threshold. Connect UVLO to an external resistor-divider to define a threshold externally and override the preset internal UVLO threshold.
12, 13, 14	OUT	Switch Output. Bypass OUT to GND with a 4.7 μ F ceramic capacitor placed as close to the device as possible.
16	RIPEN	Reverse-Current Protection Enable. Internally pulled up. Connect RIPEN to GND with 10k Ω resistor or lower to disable the reverse-current flow protection.
17	$\overline{\text{HVEN}}$	60V Capable Active-Low Enable Input. See Table 1.
18	CLTS2	Current-Limit Type Select 2. See Table 2.
19	CLTS1	Current-Limit Type Select 1. See Table 2.
20	EN	Active-High Enable Input. See Table 1.
—	GND/EP	Ground/Exposed Pad. Connect to a large copper ground plane to maximize thermal performance.

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Functional Diagram



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Detailed Description

The MAX14721–MAX14723 adjustable overvoltage, undervoltage, and overcurrent protection devices guard systems against overcurrent faults in addition to positive overvoltage and reverse-voltage faults. When used with an optional external p-channel MOSFET, these devices also protect downstream circuitry from voltage faults up to +60V, -60V (for -60V external pFET rating). The MAX14721–MAX14723 feature a low, 76mΩ, on-resistance integrated FET. During startup, the devices are designed to charge large capacitances on the output in a continuous mode for applications where large reservoir capacitors are used on the inputs to downstream devices. Additionally, the MAX14721, MAX14722, and MAX14723 feature a dual-stage current-limit mode in which the current is continuously limited to 1x, 1.5x, and 2x the programmed limit, respectively, for a short time after startup. This enables faster charging of large loads during startup.

The MAX14721–MAX14723 feature the option to set the overvoltage lockout (OVLO) and undervoltage lockout (UVLO) thresholds manually using external voltage dividers or to use the factory-preset internal thresholds by connecting the OVLO and/or UVLO pin(s) to GND. The permitted overvoltage lockout set point range of the devices is 6V to 40V, while the permitted undervoltage lockout set point range is 5.5V to 24V. Therefore, the pFET and internal nFET must be kept off in the 40V to 60V range by appropriate OVLO resistor divider.

The devices' programmable current-limit threshold can be set for currents up to 2A in autoretry, latching, or continuous fault response mode. When the device is set to autoretry mode and the current exceeds the threshold for more than 24ms (typ), both FETs are turned off for 720ms (typ), then turned back on. If the fault is still present, the cycle repeats. In latching mode, if a fault is present for more than 24ms (typ), both FETs are turned off until enable is toggled or the power is cycled. In continuous mode, the current is limited continuously to the programmed current-limit value. In all modes, FLAG asserts if $V_{IN} - V_{OUT}$ is greater than the FLAG assertion drop voltage threshold (V_{FA}).

Startup Control

These devices feature a dual-stage startup sequence that continuously limits the current to 1x/1.5x/2x the set current limit during the startup initial time (t_{STI}), allowing large capacitors present on the output of the switch to be rapidly charged. The MAX14721 limits the current to 1x the set limit during this period while the MAX14722 and MAX14723 limit the current to 1.5x and 2x the set limit, respectively. If the temperature of any device rises to the thermal foldback threshold (T_{J_FB}), the device will enter

power-limiting mode (Figure 1). In this mode, the device thermally regulates the current through the switch in order to protect itself while still delivering as much current as possible to the output regardless of the current limit type selected. If the output is not charged within the startup timeout period (t_{STO}), the switch turns off and IN, EN, or HVEN must be toggled to resume normal operation.

The MAX14721–MAX14723 have a 16ms (typ) time delay at the end of startup, during which the reverse threshold is set at -90mV (typ) to prevent false reverse faults due to oscillation. After this delay, the reverse current-blocking threshold is reduced to -9mV (V_{RIB} , typ).

Overvoltage Lockout (OVLO)

The devices feature two methods for determining the OVLO threshold. By connecting the OVLO pin to GND, the preset internal OVLO threshold of 36V (typ) is selected. If the voltage at OVLO rises above the OVLO select threshold (V_{OVLO_SEL}), the device enters adjustable OVLO mode. Connect an external voltage divider to the OVLO pin as shown in the [Typical Application Circuit](#) to adjust the OVLO threshold. The permitted overvoltage lockout set point range of the device is 6V to 40V. $R3 = 2.2M\Omega$ is a good starting value for minimum current consumption. Since V_{SET} is known (1.22V, typ), $R3$ has been chosen, and V_{OVLO} is the target OVLO value, $R4$ can then be calculated by the following equation:

$$R4 = \frac{R3 \times V_{SET}}{V_{OVLO} - V_{SET}}$$

Undervoltage Lockout (UVLO)

The devices feature two methods for determining the UVLO threshold. By connecting the UVLO pin to GND, the preset, internal UVLO threshold of 12V (typ) is selected. If the voltage at UVLO rises above the UVLO select threshold (V_{UVLO_SEL}) the device enters adjustable UVLO mode. Connect an external voltage divider to the UVLO pin as shown in the [Typical Application Circuit](#) to adjust the UVLO threshold. The permitted undervoltage lockout set point range of the device is 5.5V to 24V. $R1 = 2.2M\Omega$ is a good starting value for minimum current consumption. Since V_{SET} is known (1.22V, typ), $R1$ has been chosen, and V_{UVLO} is the target value, $R2$ can then be calculated by the following equation:

$$R2 = \frac{R1 \times V_{SET}}{V_{UVLO} - V_{SET}}$$

Switch Control

There are two independent enable inputs on the devices: \overline{HVEN} and EN. \overline{HVEN} is a high-voltage-capable input,

Table 1. Enable Inputs

$\overline{\text{HVEN}}$	EN	SWITCH STATUS
0	0	ON
0	1	ON
1	0	OFF
1	1	ON

accepting signals up to 60V. EN is a low-voltage input, accepting a maximum voltage of 5V. In case of a fault condition, toggling $\overline{\text{HVEN}}$ or EN resets the fault. The enable inputs control the state of the switch based on the truth table (Table 1).

Input Debounce

The MAX14721–MAX14723 feature a built-in input debounce time (t_{DEB}). The debounce time is a delay between a POR event and the switch being turned on. If the input voltage rises above the UVLO threshold voltage or if, with a voltage greater than V_{UVLO} present on IN, the enable pins toggle to the on state, the switch turns on after t_{DEB} . In cases where the voltage at IN falls below V_{UVLO} before t_{DEB} has passed, the switch remains off (Figure 2). If the voltage at OUT is already above $V_{\text{UVLO_OUT}}$ when the device is turned on through either enable pin or coming out of OVLO, there is no debounce interval. This is due to the device already being out of the POR condition with OUT above $V_{\text{UVLO_OUT}}$.

Current-Limit Type Select

The MAX14721–MAX14723 feature three selectable current-limiting modes. During power-up, all devices default to continuous mode and follow the procedure defined in the [Startup Control](#) section. Once the part has been successfully powered on and t_{STO} has expired, the device senses the condition of CLTS1 and CLTS2. The condition of CLTS1 and CLTS2 sets the current-limit mode type according to Table 2. CLTS1,2 are internally pulled up to an internal 5V supply. Therefore, the device is in continuous current-limit mode when CLTS1 and CLTS2 are open. To set CLTS_ state to low, connect a 10k Ω resistor or below to ground.

In addition to the selectable current-limiting modes, the device has a protection feature against a severe over load condition. If the output current exceeds 2 times the set current limit, the device will turn off the internal nFET and external pFET immediately and will attempt to restart to allow the overcurrent to last for t_{BLANK} time. The OFF duration depends on fault condition occurred after the FETs turn off, with the shortest duration of 420 μs ($t_{\text{ON_FET}}$)

Table 2. Current-Limit Type Select

CLTS2	CLTS1	CURRENT-LIMIT TYPE
0	0	LATCHOFF MODE
0	1	AUTORETRY MODE
1	0	CONTINUOUS MODE
1	1	CONTINUOUS MODE

if there is no fault. In Latchoff mode, the device will latch off if the overcurrent fault last longer than t_{BLANK} .

Autoretry Mode (Figure 3)

In autoretry current-limit mode, when current through the device reaches the threshold, the t_{BLANK} timer begins counting. The $\overline{\text{FLAG}}$ output asserts low when the voltage drop across the switch rises above V_{FA} . If the overcurrent condition is present for t_{BLANK} , the switch is turned off. The timer resets if the overcurrent condition disappears before t_{BLANK} has elapsed. A retry time delay (t_{RETRY}) starts immediately once t_{BLANK} has elapsed. During the retry time, the switch remains off and, once t_{RETRY} has elapsed, the switch is turned back on. If the fault still exists, the cycle is repeated and $\overline{\text{FLAG}}$ remains low. If the fault has been removed, the switch stays on.

The autoretry feature reduces system power in case of overcurrent or short-circuit conditions. When the switch is on during t_{BLANK} time, the supply current is held at the current limit. When the switch is off during t_{RETRY} time, there is no current through the switch. Thus, the output current is much less than the programmed current limit. Calculate the average output current using the following equation.

$$I_{\text{LOAD}} = I_{\text{LIM}} \left[\frac{t_{\text{BLANK}} + t_{\text{STI}} \times K}{t_{\text{BLANK}} + t_{\text{RETRY}} + t_{\text{STI}}} \right]$$

where K is the multiplication factor of the initial current limit (1x, 1.5x or 2x). With a 24ms (typ) t_{BLANK} , 24ms t_{STI} , $K = 1$ and 720ms (typ) t_{RETRY} , the duty cycle is 3.1%, resulting in 97% power saving as compared to the switch being on the entire time.

Latchoff Mode (Figure 4)

In latchoff current-limit mode, when current through the device reaches the threshold, the t_{BLANK} timer begins counting. The $\overline{\text{FLAG}}$ asserts when the voltage drop across the switch rises above V_{FA} . The timer resets if the overcurrent condition disappears before t_{BLANK} has elapsed. The switch turns off if the overcurrent condition remains for the blanking time. The switch remains off until the control logic (EN or $\overline{\text{HVEN}}$) is toggled or the input voltage is cycled.

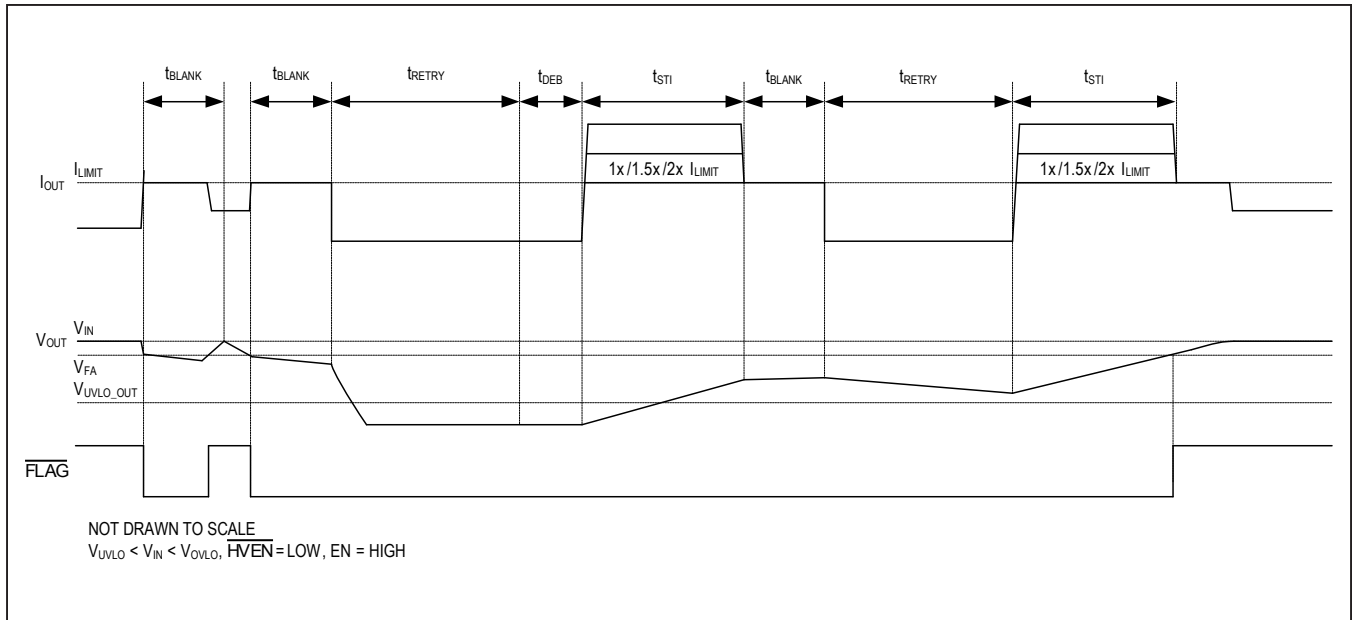


Figure 3. Autoretry Fault Diagram

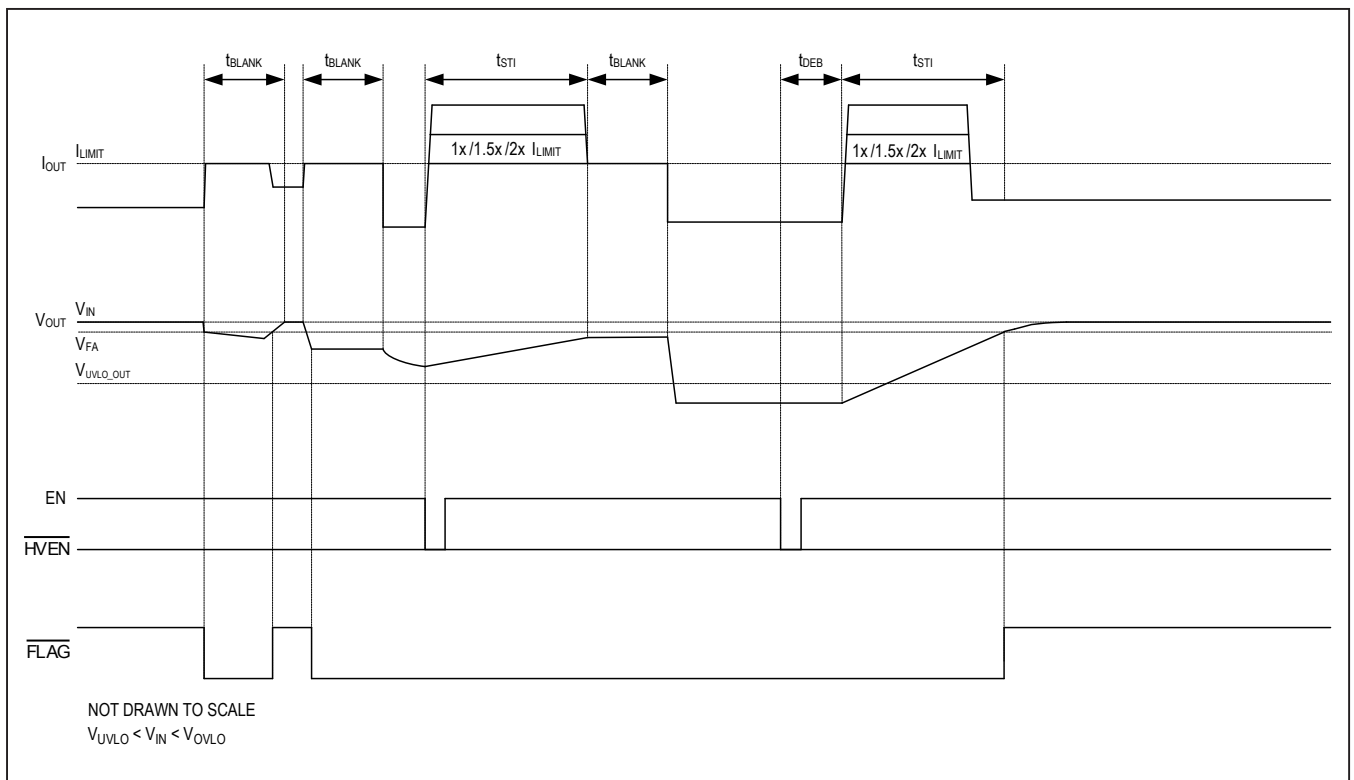


Figure 4. Latchoff Fault Diagram

Continuous Mode (Figure 5)

In continuous current-limit mode, when current through the device reaches the threshold, the device limits the current to the programmed limit. $\overline{\text{FLAG}}$ asserts when the voltage drop across the switch rises above V_{FA} , and deasserting when it falls below V_{FA} .

Reverse-Current Blocking (Figure 6)

The MAX14721–MAX14723 feature current-blocking functionality to be used with external pFET. To enable the reverse-current blocking feature, pull RIPEN high. With RIPEN high, if a reverse-current condition is detected ($V_{\text{IN}} - V_{\text{OUT}} < V_{\text{RIB}}$), the internal nFET and the external pFET are turned off for 2.4ms ($t_{\text{REV_REC}}$). During and after this

time, the device monitors the voltage difference between OUT and IN pins to determine whether the reverse current is still present. Once $t_{\text{REV_REC}}$ expired and the reverse-current condition has been removed, the nFET and pFET are turned back on after an additional time delay follows by the dual-stage startup control mechanism as defined in the Startup Control section above. The additional time delay will be 420us ($t_{\text{ON_NFET}}$) if voltage at OUT is more than or equal to $V_{\text{UVLO_OUT}}$ falling at the end of $t_{\text{REV_REC}}$ delay, otherwise the delay will be 0.5ms (t_{DEB}). After a reverse-current event, the device will attempt a restart regardless of the current-type select.

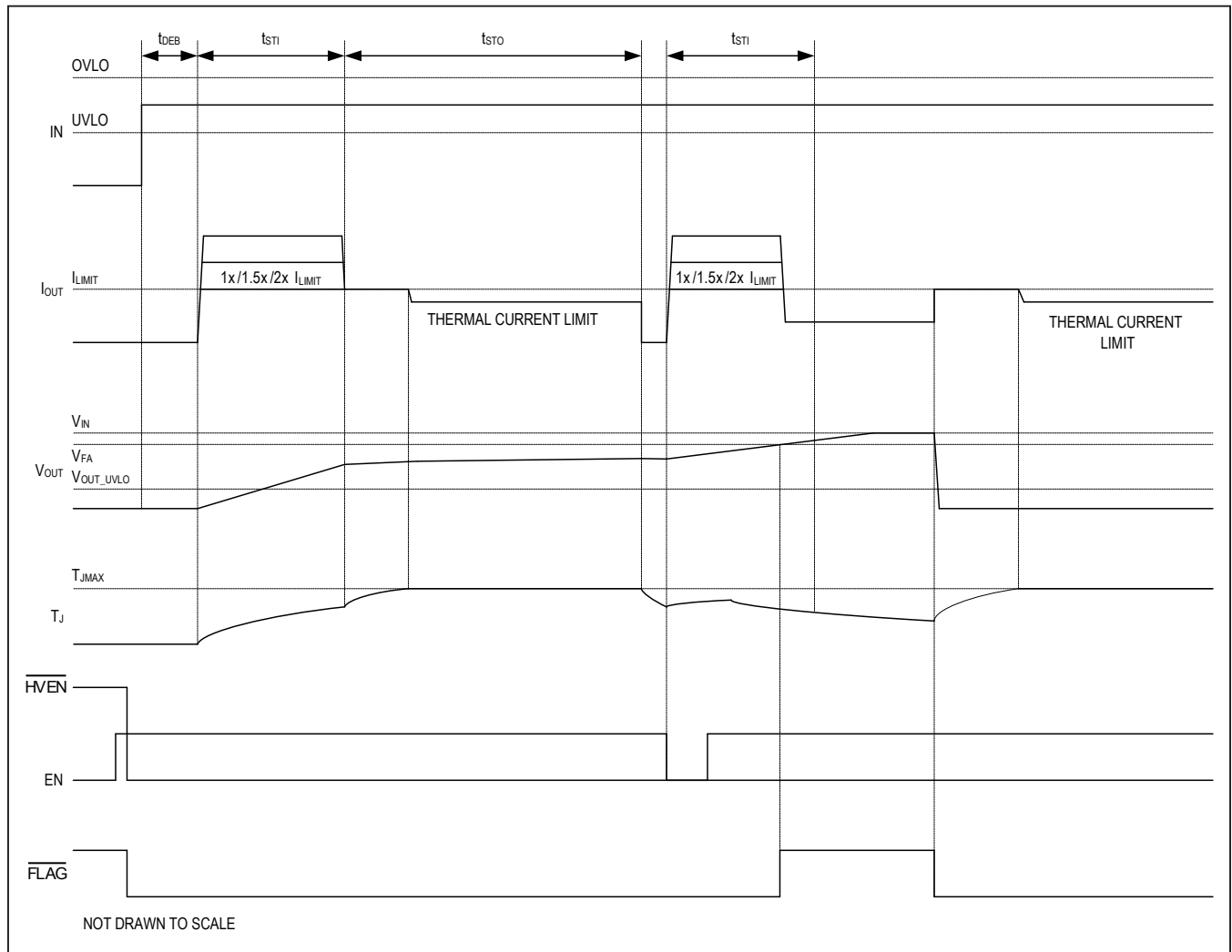


Figure 5. Continuous Fault Diagram

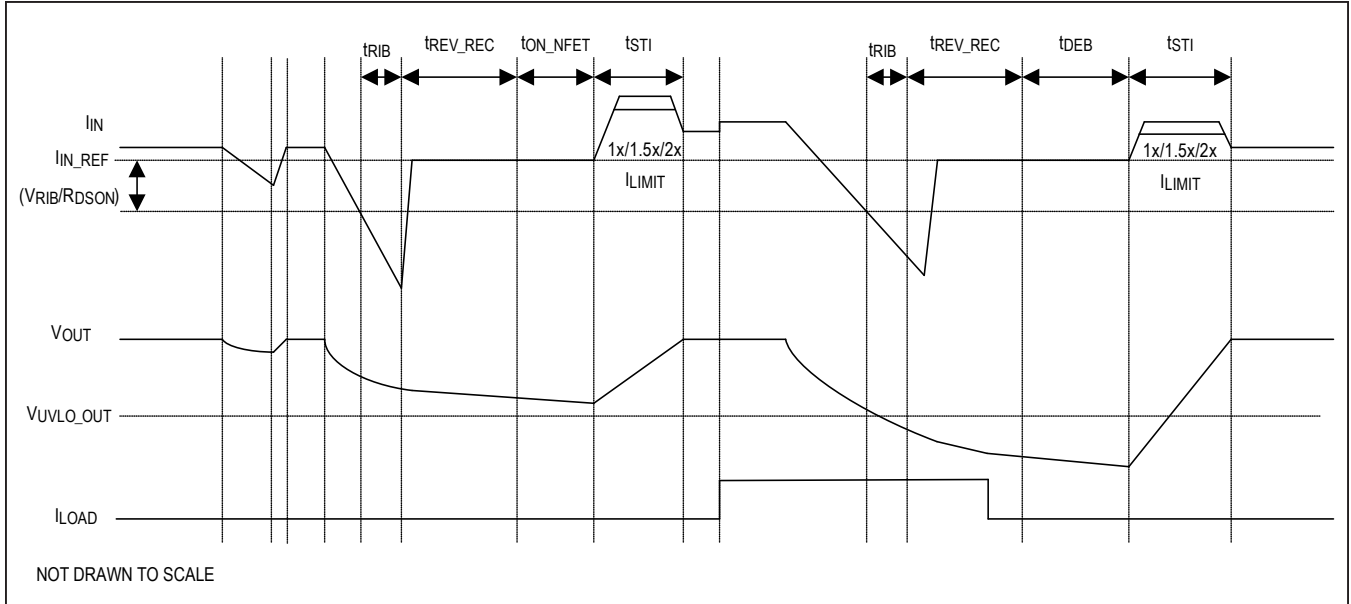


Figure 6. Reverse-Current Timing Diagram

Fault Indicator ($\overline{\text{FLAG}}$) Output

$\overline{\text{FLAG}}$ is an open-drain fault indicator output. It requires an external pullup resistor to a DC supply. $\overline{\text{FLAG}}$ asserts when any of the following conditions occur:

- $V_{\text{IN}} - V_{\text{OUT}} > V_{\text{FA}}$
- The reverse-current protection is tripped
- The die temperature exceeds +170°C
- SETI is connected to ground
- UVLO threshold has not been reached
- OVLO threshold is reached

Thermal Shutdown Protection

Thermal shutdown circuitry protects the devices from overheating. The switch turns off and $\overline{\text{FLAG}}$ asserts when the junction temperature exceeds +170°C (typ). The MAX14721–MAX14723 exit thermal shutdown and resume normal operation once the junction temperature cools by 20°C (typ) if the device is in autoretry or continuous current-limiting mode. When in latching mode, the device remains latched off until the input voltage is cycled or one of the enable pins is toggled.

The thermal-shutdown technology built into the MAX14721–MAX14723 behaves in accordance with the selected current limit mode. While the devices are in autoretry mode, the thermal limit uses the autoretry timing when coming out of a fault condition. When the MAX14721–MAX14723 detects an overtemperature fault, the switch turns off. Once the temperature of the junction falls below the falling thermal threshold, the device turns on after the time interval t_{RETRY} . In latching mode, the device latches off until the input is cycled or one of the enable pins is toggled. In continuous current-limiting mode, the device turns off while the temperature is over the limit, then turns back on after t_{DEB} when the temperature reaches the falling threshold. There is no retry time for thermal protection.

Applications Information

Setting the Current-Limit Threshold

Connect a resistor between SETI and ground to program the current-limit threshold for the MAX14721–MAX14723. Leaving SETI unconnected sets the current-limit threshold to 0A and, since connecting SETI to ground is a fault condition, this causes the switch to remain off and $\overline{\text{FLAG}}$ to assert. Use the following formula to calculate the current-limit threshold:

$$R_{\text{SETI}}(\text{k}\Omega) = \frac{V_{\text{RI}}(\Omega \times \text{A})}{I_{\text{LIM}}(\text{mA})} \times C_{\text{IRATIO}}$$

Do not use a R_{SETI} smaller than 6k Ω . Table 3 shows current-limit thresholds for different resistor values at SETI.

A current mirror with a ratio of C_{IRATIO} is implemented with a current sense auto-zero operational amplifier. The mirrored current of the IN-OUT FET is provided on the SETI pin. Therefore, the voltage (V_{SETI}) read on the SETI pin should be interpreted as the current through the IN-OUT FET, as shown below:

$$I_{\text{IN-OUT}} = I_{\text{SETI}} \times C_{\text{IRATIO}} = \frac{V_{\text{SETI}}(\text{V})}{R_{\text{SETI}}(\text{k}\Omega)} \times C_{\text{IRATIO}} = \frac{V_{\text{SETI}}(\text{V})}{V_{\text{RI}}(\text{V})} \times I_{\text{LIM}}$$

IN Bypass Capacitor

In applications in which an external PFET is not used, connect a minimum of 1 μF capacitor from IN to GND to limit the input voltage drop during momentary output short-circuit conditions. Larger capacitor values further reduce the voltage droop at the input caused by load transients.

In applications in which an external PFET is used, a 4.7 μF capacitor is placed at the drain of the PFET and capacitor at IN is reduced to 10nF (100nF, max).

Hot Plug-In

In many power applications, an input filtering capacitor is required to lower the radiated emission, enhance the ESD capability, etc. In hot plug applications, parasitic cable inductance, along with the input capacitor, causes overshoot and ringing when a powered cable is suddenly connected to the input terminal. This effect causes the protection device to see almost twice the applied voltage. An input voltage of 24V can easily exceed 40V due to ringing. The MAX14721–MAX14723 contain internal protection against hot plug input transients on the IN pins, with slew rate up to 30V/ μs . However, in the case where the harsh industrial EMC test is required, use a

Table 3. Current-Limit Threshold vs. Resistor Values

R_{SETI} (k Ω)	CURRENT LIMIT (A)
62.5	0.2
25.0	0.5
12.5	1.0
8.3	1.5
6.25	2.0

transient voltage suppressor (TVS) placed close to the

MAX14721/
MAX14722/
MAX14723

High-Accuracy, Adjustable Power Limiter

input terminal that is capable of limiting the input surge to a maximum of 60V.

OUT Capacitance

For stable operation over the full temperature range and over the entire programmable current-limit range, connect a 4.7µF ceramic capacitor from OUT to ground. Other circuits connected to the output of the device may introduce additional capacitance, but it should be noted that excessive output capacitance on the MAX14721–MAX14723 can cause faults. If the capacitance is too high, the MAX14721–MAX14723 may not be able to charge the capacitor before the startup timeout. Calculate the maximum capacitive load (C_{MAX}) value that can be connected to OUT using the following formula:

$$C_{MAX}(mF) = I_{LIM}(A) \left[\frac{M \times t_{STI}(ms) + t_{STO}(ms)}{V_{IN_MAX}(V)} \right]$$

where M is the multiplier (1x/1.5x/2x) applied to the current limit during startup. For example, when using MAX14721, if V_{IN_MAX} = 20V, t_{STO} (min) = 1090ms, t_{STI} (min) = 22ms, and I_{LIM} = 2A, C_{MAX} results in the theoretical maximum of 111mF. In this case, any capacitance larger than 111mF will cause a fault condition because the capacitor cannot be charged to a sufficient voltage before t_{STO} has expired. In practical applications, the output capacitor size is limited by the thermal performance of the PCB board. Poor thermal design can cause the thermal foldback current-limiting function of the device to kick in too early, which may further limit the maximum capacitance that can be charged. Therefore, good thermal PCB design is imperative in order to charge large capacitor banks.

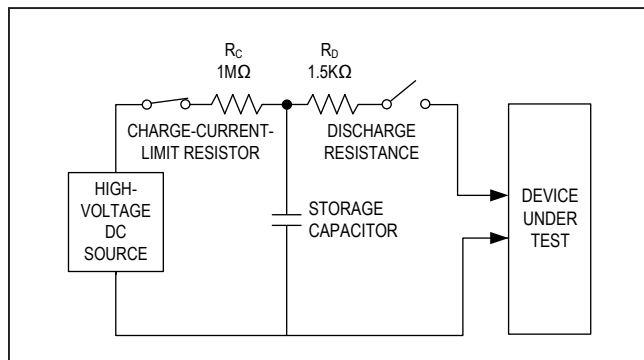


Figure 7. Human Body ESD Test Model

OUT Freewheeling Diode for Inductive Hard Short to Ground

In applications with a highly inductive load, a freewheeling diode is required between the OUT terminal and GND. This protects the device from inductive kickback that occurs during short-to-ground events.

Layout and Thermal Dissipation

To optimize the switch response to output short-circuit conditions, it is important to reduce the effect of undesirable parasitic inductance by keeping all traces as short as possible. Place input and output capacitors as close as possible to the device (no more than 5mm). IN and OUT must be connected with wide short traces to the power bus. During steady-state operation, the power dissipation is typically low and the package temperature change is usually minimal.

Attention must be given when using continuous current-limit mode. In this mode, the power dissipation during a fault condition can quickly cause the device to reach the thermal shutdown threshold. A large copper plane and multiple thermal vias from the exposed pad to ground plane are necessary to increase the thermal capacitance and reduce the thermal resistance of the board.

ESD Test Conditions

The MAX14721–MAX14723 are specified for ±15kV (HBM) ESD on IN when IN is bypassed to ground with a 1µF, low ESR ceramic capacitor. No capacitor is required for ±2kV (HBM) (typ) ESD on IN. All pins have ±2kV (HBM) ESD protection. In applications in which an external pFET is used, see IN Bypass Capacitor section.

HBM ESD Protection

Figure 7 shows the Human Body Model and Figure 8 shows the current waveform it generates when discharged into low impedance. This model consists of a 100pF capacitor charged to the ESD voltage of interest, which is then discharged into the device through a 1.5kΩ resistor.

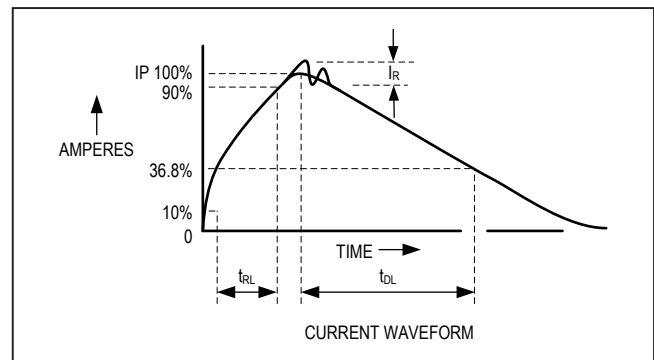
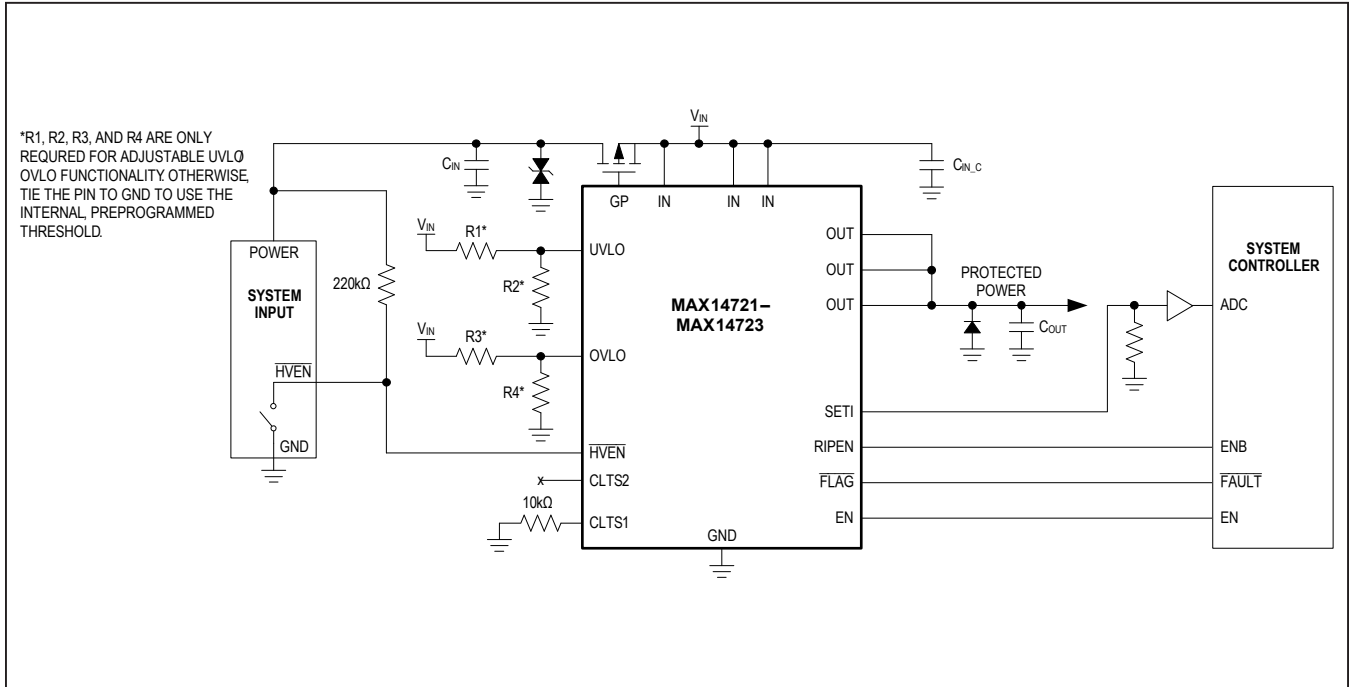


Figure 8. Human Body Current Waveform

MAX14721/
MAX14722/
MAX14723

High-Accuracy, Adjustable Power Limiter

Typical Application Circuit



Ordering Information

PART	INITIAL CURRENT LIMIT	TEMP RANGE	PIN-PACKAGE
MAX14721ATP+T	1.0x	-40°C to +125°C	20 TQFN-EP*
MAX14722ATP+T	1.5x	-40°C to +125°C	20 TQFN-EP*
MAX14723ATP+T	2.0x	-40°C to +125°C	20 TQFN-EP*

+Denotes a lead(Pb)-free/RoHS-compliant package.

T = Tape and reel.

*EP = Exposed pad.

Chip Information

PROCESS: BiCMOS